

# **XTR75030**

High Temperature Negative Voltage Regulator

# **Data Sheet**

Rev 2 - August 2021 (DS-01016-20)

# PROTOTYPE







DIP8 XTR75034 XTR75035







# DESCRIPTION

XTR75030 is a family of low-power voltage regulators/references designed for extreme reliability and high temperature applications. Being able to operate with input voltages from -35V to -3.2V, XTR75030 parts can supply up to 50mA at +230°C while providing excellent regulation characteristics. Parts from this product family operate as a 3-terminal series regulator/reference with a temperature coefficient (TC) as low as 40ppm/°C. Up to ten possible output voltages (-15V to -1.2V) can be obtained from the same part.

Functionality features include shut-down mode and soft-start.

XTR75030 parts can be used in a wide range of applications such as positive and negative regulators/references, adjustable power supply, current sources, as well as precision bridge excitation.

Special design techniques were used allowing XTR75030 parts to offer a precise, robust and reliable operation in critical applications. Full functionality is guaranteed from -60°C to +230°C, though operation well below and above this temperature range is achieved.

XTR75030 parts have been designed to reduce system cost and ease adoption by reducing the learning curve and providing smart and easy to use features.

Parts from the XTR75030 family are available in ruggedized SMT and thru-hole packages.

See also the Application Notes in the XTR75030 webpage

# **FEATURES**

- Up to 10 possible output voltages from same part: -1.2V / -1.8V / -2.5V / -3.3V / -5V / -5.5V / -9V / -10V / -12V / -15V.
- Input voltage from -35V to -3.2V.
- Drop-in replacement of commercial voltage references.
- Trimming capabilities.
- Operational beyond the -60°C to +230°C temperature range.
- Output current up to 50mA @ 230°C.
- Soft-start.
- Compatible with low and high dropout voltages. •
- Stable over a wide range of load capacitance (0.1µF to 10µF).
- Low intrinsic current consumption (380μA @ 230°C).
- Low temperature dependence (40ppm/°C). •
- Excellent line regulation (0.04%/V @ 230°C).
- Active-low shutdown control.
- Monolithic design for high-reliability.
- Latch-up free SOI process.
- Ruggedized SMT and thru-hole packages.

# **APPLICATIONS**

- Reliability-critical, Automotive, Aeronautics & Aerospace, Downhole.
- Positive and negative precision regulators/references, A/D and D/A converters, current sources, bridge excitation.

# **PRODUCT HIGHLIGHT**





# ORDERING INFORMATION

х	TR	75	03x	
		$\overline{\mathbf{V}}$	$\overline{\mathbf{v}}$	
Source:	Process:	Part family	Part number	
X = X-REL Semi	TR = HiTemp, HiRel			

Product Reference	Temperature Range	Package	Pin Count	Marking
XTR75030-TD	-60°C to +230°C	Tested bare die		
XTR75031-D	-60°C to +230°C	Ceramic side brazed DIP	16	XTR75031
XTR75031-S	-60°C to +230°C	Ceramic SOIC	16	XTR75031
XTR75034-D	-60°C to +230°C	Ceramic side brazed DIP	8	XTR75034
XTR75034-FE	-60°C to +230°C	Gull-wing flat pack with ePad	8	XTR75034
XTR75035-D	-60°C to +230°C	Ceramic side brazed DIP	8	XTR75035
XTR75035-FE	-60°C to +230°C	Gull-wing flat pack with ePad	8	XTR75035

Other packages and packaging configurations possible upon request. For some packages or packaging configurations, MOQ may apply.

# ABSOLUTE MAXIMUM RATINGS

Voltage on GND to VIN	-40 to 0.5V
Voltage on GND to VOUT	-17 to 0.5V
Voltage on GND to ENABLE	VIN-0.5 to 0.5V
Voltage on any other pin to GND	Max[-6V, VOUT] to 0.5V
Storage Temperature Range	-70°C to +230°C
Operating Junction Temperature Range	-70°C to +300°C
ESD Classification	1kV HBM MIL-STD-883

**Caution:** Stresses beyond those listed in "ABSOLUTE MAXIMUM RATINGS" may cause permanent damage to the device. These are stress ratings only and functionality of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to "ABSOLUTE MAXIMUM RATINGS" conditions for extended periods may permanently affect device reliability.

### PACKAGING



For devices with "FE" package options (CDFP8), ePAD connected to VIN.

# INTERNAL BLOCK DIAGRAM

Possible output voltages depending on packaging options.

	-1.2V	-1.8V	-2.5V	-3.3V	-5V	-5.5V	-9V	-10V	-12V	-15V
XTR75030 (bare die)	√	✓	√	✓	✓	√	✓	✓	√	✓
XTR75031	✓	✓	√	✓	✓	√	✓	✓	✓	✓
XTR75034	√	✓	√	✓						
XTR75035	✓		✓		✓				✓	







# PIN DESCRIPTION

		XTR75031		
Pin Number	Name	Description		
1	ENABLE	tive-low shut-down terminal. Connect to GND when not used.		
2	GND15V	Connect to GND to set $V_{OUT}$ =-15V.		
3	GND12V	Connect to GND to set V <sub>OUT</sub> =-12V.		
4	GND10V	Connect to GND to set V <sub>OUT</sub> =-10V.		
5	GND9V	Connect to GND to set V <sub>OUT</sub> =-9.0V.		
6	GND5V5	Connect to GND to set V <sub>OUT</sub> =-5.5V.		
7	GND	Circuit ground.		
8	VOUT_RANGE	For external gain and trimming.		
9	VOUT	Output voltage terminal. Decouple to GND with a capacitor of at least 100nF.		
10	N.C.	No internal connection.		
11	GND1V8	Connect to GND to set V <sub>OUT</sub> =-1.8V.		
12	GND2V5	Connect to GND to set $V_{OUT}$ =-2.5V.		
13	GND3V3	Connect to GND to set V <sub>OUT</sub> =-3.3V.		
14	GND5V	Connect to GND to set V <sub>OUT</sub> =-5.0V.		
15	GND	Circuit ground.		
16	VIN	Input voltage terminal.		

		XTR75034	
Pin Number Name Description		Description	
1	ENABLE	Active-low shut-down terminal. Connect to GND when not used.	
2	GND	Circuit ground.	
3	GND1V8	Connect to GND to set V <sub>OUT</sub> =-1.8V.	
4	VOUT_RANGE	For external gain and trimming.	
5	VOUT	Output voltage terminal. Decouple to GND with a capacitor of at least 100nF.	
6	GND2V5	Connect to GND to set $V_{OUT}$ =-2.5V.	
7	GND3V3	Connect to GND to set $V_{OUT}$ =-3.3V.	
8	VIN	Input voltage terminal.	

		XTR75035		
Pin Number	Name	Description		
1	ENABLE	Active-low shut-down terminal. Connect to GND when not used.		
2	GND	ircuit ground.		
3	GND2V5	Connect to GND to set $V_{OUT}$ =-2.5V.		
4	VOUT_RANGE	For external gain and trimming.		
5	VOUT	Output voltage terminal. Decouple to GND with a capacitor of at least 100nF.		
6	GND5V	Connect to GND to set $V_{OUT}$ =-5.0V.		
7	GND12V	Connect to GND to set $V_{OUT}$ =-12V.		
8	VIN	Input voltage terminal.		



## THERMAL CHARACTERISTICS

Parameter	Condition	Min	Тур	Max	Units
XTR75031-S (SOIC16)					
Thermal Resistance: J-C			22		°C/W
R <sub>Th_J-C</sub>			22		C/ VV
Thermal Resistance: J-A			120		°C/W
R <sub>Th_J-A</sub>			120		C/ W
XTR75031-D (DIL16)					
Thermal Resistance: J-C			22		°C/W
Rth_J-C			22		C/ W
Thermal Resistance: J-A			95		°C/W
RTh_J-A					C/ W
XTR7503x-D (DIL8)					
Thermal Resistance: J-C			25		°C/W
Rth_J-C			23		0,11
Thermal Resistance: J-A			100		°C/W
Rm_J-A			100		C/ W
XTR7503x-FE (DFP8 with expose	d pad)				
Thermal Resistance: J-C	Measured on ePAD.		7		°C/W
Rm_J-c					C/ VV
Thermal Resistance: J-A	ePAD thermally connected to 3cm <sup>2</sup> PCB copper		70		°C/W
R <sub>Th_J-A</sub>			10		C/ VV

# **RECOMMENDED OPERATING CONDITIONS**

Parameter	Min	Тур	Max	Units
Supply voltage <b>V<sub>IN</sub></b>	-35		-3.2	V
Output voltage <b>Vουτ</b>	-1.2		-15	V
Voltage on ENABLE to GND	Vin		0	V
Voltage on VOUT_RANGE to GND	Vout		0	V
Output current	100µA¹		ILOADMax	
Case Temperature <sup>2</sup> Tc	-60		230	°C

<sup>1</sup> A minimum output current of 100µA is recommended for stability reasons under any output voltage and temperature.

<sup>2</sup> Operation beyond the specified temperature range is achieved. The -60°C to +230°C range for the case temperature is considered for the case where no current is externally drawn from pin VDD, other than to supply the XTR75030 part.



# **ELECTRICAL SPECIFICATIONS**

Unless otherwise stated, specification applies for (VIN-VOUT)=-10V, ILOAD=10mA, -60°C<TC<230°C.

Parameter	Name	Condition	Min	Тур	Max	Units	
Output Characteristics							
				-1.2			
				-1.8			
				-2.5			
				-3.3			
Nominal Output Voltages	Vout			-5.0		V	
Nominal Output Voltages	*001			-5.5		l ·	
				-9.0			
				-10			
				-12			
				-15			
Output Voltage Accuracy	ΔVουτ/Vουτ	Tc=85°C	-5		+5	%	
		ILOAD=10mA Tc=-60°C		200	270	1	
		Tc=85°C		280	350	mV	
	64 34 31	Tc=230°C		410	540		
Dropout Voltage	(VIN-Vout) <sup>1</sup>	I <sub>LOAD</sub> =50mA T <sub>C</sub> =-60°C		1.0	1.3		
		Tc=85°C		1.4	1.8	V	
		Tc=230°C		2.7	3.0		
Drift with Temperature <sup>2</sup>	(ΔVουτ/ΔVουτ)/ΔΤ	Measured for worst case $V_{IN}$ conditions. 100µA≤l <sub>LOAD</sub> ≤50mA	15	45	75	ppm/°C	
		$V_{OUT} \ge -1.8V$ ; $V_{IN} = -2.8V$ to $-35V$					
		$V_{OUT} \le -2.5V$ ; $V_{IN} = V_{OUT} - 0.5V$ to $-35V$ $V_{OUT} \le -2.5V$ ; $V_{IN} = V_{OUT} - 0.5V$ to $-35V$					
Line Regulation <sup>2</sup>	ΔVουτ/Vουτ	V001≥-2.3V, VIN-V001-0.3V (0-33V					
Line Regulation		Tc=-60°C		0.005			
		Tc=85°C		0.005		%/V	
		T <sub>c</sub> =230°C		0.02		/0, 1	
	1	Any $V_{OUT}$ for $(V_{IN}-V_{OUT}) \leq -5V$ , T <sub>c</sub> =230°C (worst case)	50	70			
		Any $V_{OUT}$ for $(V_{IN}-V_{OUT}) \le -2V$ , $T_c=230^{\circ}C$ (worst case)	30	40			
Maximum Load Current	LOADMax	V <sub>IN</sub> =-2.8V, T <sub>C</sub> =230°C (worst case)				mA	
		V <sub>OUT</sub> =-1.2V	20	30			
		V <sub>OUT</sub> =-1.8V	15	20			
		V <sub>OUT</sub> =-2.5V	5	7			
		I <sub>LOAD</sub> =1mA to 30mA, (V <sub>IN</sub> -V <sub>OUT</sub> )=-2V. See Figure 15	İ			1	
		V <sub>out</sub> =-1.2V (TRIM connected to VOUT)		0.18	0.25		
		V <sub>out</sub> =-15V		2.25	3.10		
Load Regulation <sup>2</sup>	$\Delta V_{OUT} / \Delta I_{LOAD}$				0.10		
		$I_{\text{LOAD}}=1\text{mA to 50mA}, (V_{\text{IN}}-V_{\text{OUT}})=-5V.$ See Figure 16		0.15	0.22		
		V <sub>OUT</sub> =-1.2V (TRIM connected to VOUT)		0.15 1.90	0.22		
		V <sub>OUT</sub> =-15V		1.90	2.60		

<sup>1</sup>ΔVOUT is defined as |VOUT\_Max – VOUT\_min| within the indicated range of temperature, input voltage or load current.

<sup>2</sup> Difference between the input and output voltages that makes VOUT to deviate by 1% from its nominal value at the same load current.

<sup>2</sup> Difference between the input and output voltages that makes volt to deviate by 1/0 from its means  $\frac{1}{T_{MAX}-T_{MIN}}$ <sup>3</sup> The drift is defined as the following equation: temperature\_drift =  $1e6 \times \frac{V_{OUT}(T_{MAX})-V_{OUT}(T_{MIN})}{V_{OUT,NOMINAL}} \times \frac{1}{T_{MAX}-T_{MIN}}$ 

<sup>4</sup> The line regulation is defined as the following equation Line\_reg =  $100 \times \frac{V_{OUT,NOMINAL}}{V_{OUT,NOMINAL}} \times \frac{V_{OUT,NOMINAL}}{V_{OUT,NOMINAL}}$  $\frac{1}{V_{IN\_MAX} - V_{IN\_MIN}}$ <sup>5</sup> Worst case: TC=230°C

 ${}^{6} The \ load \ regulation \ is \ defined \ as \ the \ following \ equation: Load\_reg = \frac{V_{OUT}(I_{LOAD\_MIN}) - V_{OUT}(I_{LOAD\_MAX})}{I_{LOAD\_MIN} - I_{LOAD\_MAX}}$ 



# **ELECTRICAL SPECIFICATIONS (CONTINUED)**

Unless otherwise stated, specification applies for (V<sub>IN</sub>-V<sub>OUT</sub>)=-10V, I<sub>LOAD</sub>=10mA, -60°C<T<sub>C</sub><230°C.

Parameter	Name	Condition	Min	Тур	Max	Units
Supply Current						
		V <sub>OUT</sub> =-5.0V T <sub>C</sub> =-60°	С	200	250	
Quiescent Ground Current		Tc=85°C	C	300	360	μΑ
		Tc=230	°C	380	480	
Shut-down Mode Current	la.u.	V <sub>IN</sub> =-35V T <sub>C</sub> =85°C	2	25	40	μA
Shut-down Mode Current	Istd-by	Tc=230	°C	38	60	μΑ
Shut-down Mode						
Enable Voltage	Von	V <sub>IN</sub> from -2.8V to -35V		1.8	2.3	V
	/SHDN going up. Worst case for $I_c$ =-60°C.				2.10	
Shut-down Voltage	VOFF	V <sub>IN</sub> from -2.8V to -35V	0.6	0.9		V
	VOR	/SHDN going down. Worst case for $T_c=230^{\circ}C$ .	0.0	0.5		· ·
Shut-down Hysteresis	Vsdh	/SHDN going up then down.	0.2	0.4		V
/SHDN Current	1.	V <sub>/SHDN</sub> =0V	-6		0	1.
, ·	I/shdn	V/SHDN=-5V	-5		1	μA
Dynamic Characteristics		· · · · · · · · · · · · · · · · · · ·				
		V stops up from 0//to 10// See Figure 27				
		$V_{IN}$ steps up from 0V to -10V. See Figure 27 /SHDN connected to VIN, $C_{LOAD}=1\mu F$ , $T_{C}=-60^{\circ}C$ (worst case)				
Turn-ON Time vs. VIN	ton-vin	Vout=-1.2V				
		Vout=-1.2V Vout=-5V		10		
		V <sub>OUT</sub> =-5V		500		μs
		/SHDN steps up from -0.6V to -2.3V. See Figure 28				
Turn-ON Time vs. /SHDN	ton-shon	V <sub>IN</sub> =-10V, C <sub>LOAD</sub> =1µF T <sub>C</sub> =-60°C (worst case)				
Tum-ON Time vs. / SHDN	CON-SHDN	V <sub>OUT</sub> =-1.2V		35		μs
		Vout=-5V		550		μs
Input Voltage Rejection	PSRR	Freq=1kHz		-50		dB
Input Capacitance <sup>1</sup>	Cin			1		μF
Load Capacitance <sup>1</sup>	Солт		0.1	1	10	μF
Noise Characteristics	1			1	1	
		$V_{IN}$ =-10V, $V_{OUT}$ =-5.0V, $C_{IN}$ = $C_{OUT}$ =1 $\mu$ F, $I_{LOAD}$ = $\leq$ 50mA				
		BW=0.1Hz to 10Hz. T <sub>C</sub> =-60°	с	93		
Integrated Voltage Noise	Vn	Tc=85°0	C	56		
integrated voltage NOISE	۷n	Tc=230	°C	35		
		BW=10Hz to 100kHz. T <sub>C</sub> =-60°	с	181		μV <sub>rms</sub>
		T <sub>c</sub> =85°0	C	144		
		Tc=230	°C	134		
		VIN=-10V, VOUT-=-5.0V, CIN=1µF, COUT=1µF.				
Spectral Density		I <sub>LOAD</sub> =0 to 50mA, 100Hz. T <sub>C</sub> =-60°	C	6.7		
spectral Density		Tc=85°0	c	3.6		μV/VH
		Tc=230	°C	2.8		

<sup>1</sup> For stability reasons, input and load capacitances must be of ceramic type with low ESR ( $\leq 1\Omega$ ) and connected as close as possible to the part, from the input and output nodes to ground.



YPICAL PERFORMANCE	
Figure 1. Ground Current ( $I_{GND}$ ) vs Case Temperature in active mode.	Figure 2. Stand-by current (I <sub>std-by</sub> ) vs Case Temperature (/SHDN=LOW).
Figure 3. Output Voltage (Vout) vs Case Temperature. ILOAD=10mA,	Figure 4. Output Voltage (Vout) vs Case Temperature. ILOAD=10mA,
normalized to V <sub>ouτ</sub> =1,2V.	normalized to V <sub>our</sub> =5,0V.

temperatures.  $I_{LOAD}=0.1$ mA, normalized to  $V_{OUT}=1,2V$ .

Figure 6. Zoom on the start-up showing Output Voltage ( $V_{OUT}$ ) vs Input Voltage for different case temperatures. ILOAD=0.1mA, normalized to  $V_{OUT}$ =1,2V.



# TYPICAL PERFORMANCE (CONTINUED)

Figure 7. Output Voltage (V <sub>OUT</sub> ) vs Input Voltage for different case	Figure 8. Zoom on the start-up showing Output Voltage ( $V_{OUT}$ ) vs Input
temperatures. $I_{LOAD}$ =10mA, normalized to $V_{OUT}$ =1,2V.	Voltage for different case temperatures. ILOAD=10mA, normalized to
	V <sub>OUT</sub> =1,2V.
Figure 9. Output Voltage ( $V_{OUT}$ ) vs Input Voltage for different case temperatures. I <sub>LOAD</sub> =0.1mA, normalized to $V_{OUT}$ =5V.	Figure 10. Zoom on the start-up showing Output Voltage ( $V_{OUT}$ ) vs Input Voltage for different case temperatures. $I_{LOAD}$ =0.1mA, normalized to
	V <sub>OUT</sub> =5V.
Figure 11 Output Voltage (Vour) vs Input Voltage for different case	Figure 12, Zoom on the start-up showing Output Voltage (Vour) vs Input

Figure 11. Output Voltage (V<sub>OUT</sub>) vs Input Voltage for different case temperatures.  $I_{LOAD}$ =10mA, normalized to V<sub>OUT</sub>=5V.

Figure 12. Zoom on the start-up showing Output Voltage (V<sub>OUT</sub>) vs Input Voltage for different case temperatures.  $I_{LOAD}$ =10mA, normalized to V<sub>OUT</sub>=5V.





temperatures. Vout=1.2V, (VIN-VOUT)=2V.

Figure 18. Output Voltage ( $V_{\text{OUT}}$ ) vs Load Current for different case temperatures. Vout=1.2V, (VIN-VOUT)=5V.





Figure 23. Start-up at Vour=1.2V for several case temperatures when /SHDN swept from 0.5V to 2.3V.  $V_{IN}$ =10V,  $C_{OUT}$ =1 $\mu$ F,  $I_{LOAD}$ =10mA. Overlap of curves from 10 different devices.

Figure 24. Start-up at V<sub>OUT</sub>=15V for several case temperatures when /SHDN swept from 0.5V to 2.3V. V<sub>IN</sub>=20V, C<sub>OUT</sub>=1 $\mu$ F, I<sub>LOAD</sub>=10mA. Overlap of curves from 10 different devices.



# **TYPICAL PERFORMANCE (CONTINUED)**



Figure 25. Start-up at V<sub>OUT</sub>=1.2V for several case temperatures when V<sub>IN</sub> swept from 0V to 10V. /SHDN connected to VIN, C<sub>OUT</sub>=1 $\mu$ F, I<sub>LOAD</sub>=10mA. Overlap of curves from 10 different devices.

Figure 26. Start-up at V<sub>OUT</sub>=15V for several case temperatures. V<sub>IN</sub> swept from 0V to 20V. /SHDN connected to VIN, C<sub>OUT</sub>=1 $\mu$ F, I<sub>LOAD</sub>=10mA. Overlap of curves from 10 different devices.



Figure 27. Start-up time vs nominal output voltage for several case temperatures when  $V_{IN}$  is swept from 0V to 10V. /SHDN connected to VIN,  $C_{OUT}=1\mu F$ ,  $I_{LOAD}=10mA$ .

Figure 28. Start-up time vs nominal output voltage for several case temperatures when /SHDN is swept from  $V_{OFF}$ =0.6V to  $V_{ON}$ =2.3V with  $V_{IN}$  constant.  $C_{OUT}$ =1 $\mu$ F,  $I_{LOAD}$ =10mA.



### THEORY OF OPERATION

#### Introduction

#### Product description

The XTR75030 is a full CMOS series voltage regulator able to operate from -60°C to +230°C, with input voltages from -2.8V to -35V. Depending on packaging options, up to ten different output voltages from the same part (XTR75031) or pin-to-pin compatibility with other commercial voltage references can be obtained.

An active LOW shut-down functionality feature is provided, helping reduce power consumption in power-critical applications. A trimming input allows a fine tuning of the output voltage to the desired value.

#### Using the XTR75031 and XTR75032

The XTR75031 is the full-featured version in the family. All voltages are available from the same 16-pin package, so there is no need to order a XTR75031 with given output voltage.

The XTR75032 has a preselected output voltage and must be ordered with the variant code corresponding to the desired output voltage (see the Ordering Information section).

To select an output voltage in the XTR75031, just connect to GND the terminal corresponding to the desired output voltage.

The following two figures show how to use the XTR75031 (in DIP16 or SOIC16 packages) in order to provide output voltages of -3.3V and - 10V. In each case, the terminal corresponding to the desired output voltage is connected to GND. By doing this, the appropriate resistor tap (see internal diagram of XTR75031 in the Internal Block Diagram section) is grounded, thus providing the appropriate division factor in the feedback.





Figure 30. Application of XTR75031 providing 10V.

The usage of the XTR75032 is straightforward as no setting is needed from the user in order to obtain the desired output voltage (preset at assembly phase).



Figure 31. Application of XTR75032.

#### Input and output bypassing

Appropriate input bypassing is mandatory with the use of every linear regulator as the XTR75031 and XTR75032. This bypassing is needed in order to filter out input noise and provide a low AC impedance power supply to ensure stability.

In the final application, in general, the power supply is well decoupled and the parasitic inductance between the power supply and the regulator's input is low.

However, during the first evaluations of a product in the laboratory, it may happen that the part is just placed on a breadboard connected to a power supply by means of relatively long cables. In this case, the equivalent circuit would be as shown in Figure 32.



Figure 32. Non-optimum breadboard connection with voltage regulator.



Figure 33. Better breadboard connection with voltage regulator.





Figure 34. Preferred breadboard connection with voltage regulator.

The role of  $R_{IN}$  in Figure 33 and Figure 34 is to reduce the quality factor of the LC input circuit and provide a damping factor.

Use values for  $C_{\text{IN}}$  starting from 50-100nF and  $C_{\text{OUT}}$  values between  $0.1\mu\text{F}$  to  $10\mu\text{F}.$ 

#### C<sub>IN</sub>> 50-100nF

#### $100nF < C_{OUT} < 10\mu F$

These capacitors are required with low ESR-ESL and as close as possible from the XTR75030 parts. Then other capacitors with larger ESR-ESL can be used in parallel to the main input and output bypassing capacitors.

# General Considerations

# Thermal considerations

The XTR75030 has no internal thermal shutdown feature, allowing it to operate even above the -60°C to +230°C range. The user must ensure that the junction temperature does not exceed the temperature indicated in the Absolute Maximum Ratings and remain within the recommended temperature range whenever possible. Functionality can be achieved up to nearly 250°C at the expenses of reducing product lifetime.

Notice that there is no short circuit current limitation. The maximum short circuit current depends on input and output voltages, as well as on initial ambient temperature, being able to exceed 150mA in certain cases.

#### Ground connection

The XTR75030 ground pin should always be connected to the supply ground prior applying any input voltage. Accidental disconnecting of the ground terminal under operation could damage the part and its load.

#### Regulator input shorting

For a nominal output voltage V<sub>OUT</sub> $\leq$ -2.5V, connecting the input voltage to ground while the output capacitance is fully charged can create a large reverse current through the regulator pass element. If the load capacitance is large enough, the reverse current duration can be such that the regulator gets damaged.

#### Current sinking capabilities

XTR75030 parts **are not able** to source any current. Doing so would pull the output voltage above its nominal value and could damage the regulator and its load.

#### Minimum input voltage

The minimum input voltage required for a correct operation of the internal circuitry is -2.8V. In other words, to be within specifications,  $V_{\rm IN}$  should be larger than Min[V\_{OUT}-dropout,-2.8V] where the dropout value depends on the required output current.

#### Dropout

The minimum dropout of the regulator is a function of the load current, temperature and the minimum desired line regulation.

The architecture of the regulator is such that the line regulation remains at very low values even for the maximum allowed input voltage. However, thermal aspects must be considered as to not overheating the parts.

# Functional Features

### Start-up and transient behavior

The start-up of the regulator is guaranteed over the whole operating temperature range. Once in operation, the input voltage should not present large and fast negative voltage steps (5V with slopes higher than 100V/ms). Large and fast negative steps on VIN could briefly turn off the regulator.

As most linear voltage regulators, the line rejection decreases at higher frequencies so that a large and fast VIN step could generate a large transient on the regulator output and damage its load.

At start-up, the regulator needs to charge the output capacitance to V<sub>OUT</sub>. Internal provisions are made to have the regulator to present a soft-start phase. This gives a soft ramp-up of the output voltage. However, at start-up, some output overshoot (350mV) can be observed for V<sub>OUT</sub>=-1.2V when using a low-value load capacitance (100nF) and a large and fast positive step on VIN (5V with slopes higher than 100V/ms). The overshoot duration is observed to last for about 10-20µsec. However, for a load capacitance of 1µF or higher, there is no observable overshoot on the output, even for the -1.2V mode.

#### Shut-down functionality

Shut-down feature allows to securely turn off the regulator when a voltage higher than -0.6V is applied on /SHDN terminal (a current up to  $8\mu$ A can go out of this lead in this condition). In such condition, the regulator output goes to high impedance and the residual current consumption of the regulator is below 10% of the nominal operation current consumption.

In order to turn the regulator on, the /SHDN input must see a voltage of at least -2.3V (with a possible input current of up to 1 $\mu$ A). The /SHDN input must be directly connected to VIN if not used.

Considerations concerning possible output overshoot when /SHDN is pulled-up are the same than the one mentioned earlier at VIN start-up. Start-up times when using the /SHDN input control are quite similar to those obtained by applying a VIN ramp-up.

#### Stability

The regulator is stable as long as it sees the minimum required input and load capacitance with an ESR  $\leq 1\Omega$  placed as close as possible from the VIN and VOUT nodes to GND. Other capacitors with any ESR can further be added in parallel at some distance from the regulator.

To ensure the part is stable for any output voltage and under any input voltage and temperature conditions, a minimum load current of  $100\mu A$  is recommended.

When selecting  $V_{OUT}$ =-1.2V, it is recommended to connect terminal TRIM to terminal VOUT. This not only improves the stability region, also it greatly improves the load regulation.

#### Output voltage trimming

XTR75030 parts can be used as voltage regulators or as references due to their intrinsic very good stability against input voltage, load current and temperature variations.

When a highly accurate output voltage is needed, parts in the XTR75030 family have a terminal which allows the final user to fine trim the output voltage: the TRIM terminal.

The TRIM terminal has an input impedance of  $10k^{2}$  which allows modifying the feedback ratio, hence changing the output voltage.





From the block diagram it can be seen that, if the TRIM feature is not used (left floating), the nominal output voltage is given by

$$V_{OUT\_NOM} = -1.2V \cdot \left(1 + \frac{R_1}{R_2}\right)$$

The following figure shows a regulator with fine trimming feature used.



Terminal "XX" represents any terminal from "-1.8V" to "-15V". In this case the exact output voltage is given by

$$V_{OUT} = \frac{\left(R_{A//B} + 10k\Omega\right) \cdot \frac{V_{OUT\_NOM}}{-1.2V} + 100k\Omega}{10k\Omega + R_{A//B} \cdot \left(1 + \frac{100k\Omega}{R_A}\right)} \cdot V_{REF\_ACTUAL}$$

 $V_{\text{OUT\_NOM}}$  is the nominal output voltage,  $V_{\text{REF\_ACTUAL}}$  is the actual (untrimmed) internal reference voltage (-1.2V±2%) and  $R_{A//B}$  is the parallel reduction of  $R_A$  and  $R_B$ . The following table shows the value of  $R_B$  for  $R_A=100 \text{k}$ , supposing a spread of ±2% on nominal value of the reference voltage.

V	R <sub>8</sub> (k₂)		
VOUT_NOM	V <sub>REF_NOM</sub> -2%	V <sub>REF_NOM</sub> +2%	
-1.8V	176.67	228.86	
-2.5V	84.92	100.66	
-3.3V	53.24	61.43	
-5.0V	29.64	33.66	
-5.5V	26.21	29.72	
-9.0V	14.44	16.39	
-10V	12.78	14.54	
-12V	10.39	11.87	
-15V	8.10	9.33	

See also <u>product webpage</u> for Application Notes on how to trim and get different output voltages from the XTR75030.



### **PACKAGE OUTLINES**

Dimensions shown in mm [inches]. Tolerances ±0.13 mm [±0.005 in] unless otherwise stated.



88888888

2.41 ±0.25 [0.095 ±0.010]

14x 1.27 [0.050] 8.89 ±0.15

8 0.64 [0.025]

16x 0.42 ±0.05 [0.017 ±0.002]

0.30 Max [0.012 Max]







Part Marking Convention		
Part Reference:	ХТКРРРРР	
XTR	X-REL Semiconductor, high-temperature, high-reliability product (XTRM Series).	
PPPPP	Part number (0-9, A-Z).	
Unique Lot Assembly Code: YYWWANN		
YY	Two last digits of assembly year (e.g. 11 = 2011).	
WW	Assembly week (01 to 52).	
Α	Assembly location code.	
NN	Assembly lot code (01 to 99).	



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